NPN Epitaxial Planar Silicon Transistor



2SC4909

# **Muting Circuits, Drivers**

#### **Features**

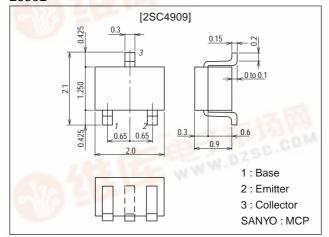
- · High DC current gain.
- · On-chip bias resistance ( $R_1$ =47k $\Omega$ ,  $R_2$ =47k $\Omega$ ).

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- · Very small-sized package permitting 2SC4909-applied sets to be made smaller and slimmer.
- · Small ON resistance.

### **Package Dimensions**

unit:mm 2059B



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

	4.64			
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		25	V
Collector-to-Emitter Voltage	VCEO		20	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	pill	10	V
Input Voltage	VIN	and the	18	V
Collector Current	I <sub>C</sub>	and Comment	100	mA
Collector Current (Pulse)	I <sub>CP</sub>	AND AND THE W	200	mA
Base Current	I <sub>B</sub>	A 132 L L	20	mA
Collector Dissipation	PC	(C)   (a)   (b)   (c)   (c)	200	mW
Junction Temperature	Tj	-34	150	°C
Storage Temperature	Tstg	D. P.	-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =20V, I <sub>E</sub> =0		J. 158	0.1	μΑ
	ICEO	V <sub>CE</sub> =15V, I <sub>B</sub> =0			0.5	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0	3	0 53	80	μΑ
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =5mA	20	0		
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA		240		MHz

Marking: JN

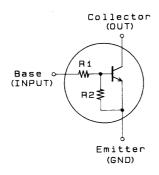
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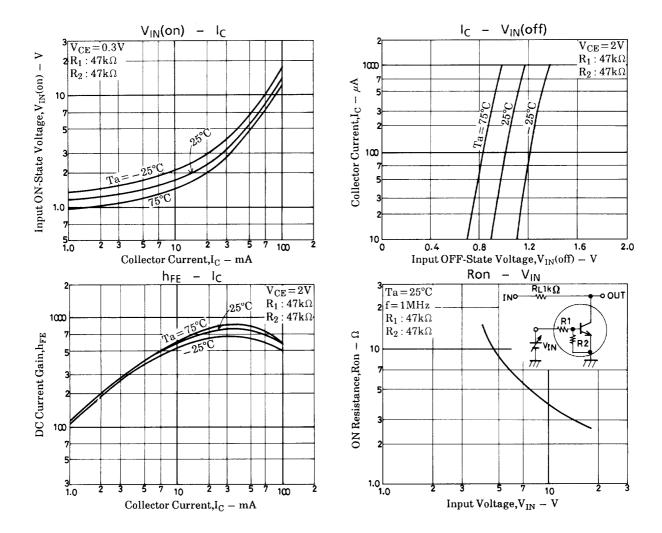
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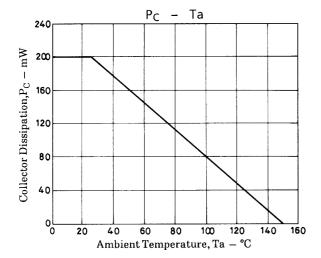
### 2SC4909

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =2mA, I <sub>B</sub> =0.2mA		10	30	mV
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	25			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	20			V
Input OFF-State Voltage	V <sub>IN</sub> (off)	V <sub>CE</sub> =2V, I <sub>C</sub> =100μA	0.7	1.0	1.4	V
Input ON-State Voltage	V <sub>IN</sub> (on)	$V_{CE}$ =0.3V, $I_{C}$ =5mA	1.0	1.5	3.0	V
Input Resistance	R <sub>1</sub>		32	47	62	kΩ
Resistance Ratio	R <sub>1</sub> /R <sub>2</sub>		0.9	1.0	1.1	
ON Resistance	Ron	V <sub>IN</sub> =10V, f=1MHz		4.0		Ω

#### **Electrical Connection**







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